# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IFW

Applicant(s): MAMITSU et al.

Serial No.: 10/699,954

Filed: November 4, 2003

Title: SEMICONDUCTOR DEVICE HAY

RADIATION STRUCTURE

Atty. Dkt.: 01-103-CON2

Group Art Unit: 1765

Examiner: Unknown

Commissioner for Patents Arlington, VA 22202

Date: October 14, 2004

### **INFORMATION DISCLOSURE STATEMENT**

Sir:

Pursuant to 37 C.F.R. §1.56, the references listed on the attached Form PTO-1449 are being submitted for consideration by the Examiner without any admission that they constitute statutory prior art, or without any admission that they contain subject matter that anticipates the invention or renders the invention obvious to a person of ordinary skill in the art.

Further, pursuant to 37 C.F.R. §1.97(e)(2), the undersigned hereby certifies that no item of information contained in the information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application, and to the knowledge of the undersigned after making reasonable inquiry, no item of information contained in the information disclosure statement was known to any individual designated in §1.56(c) more than three months prior to the filing of the information disclosure statement. Please note that US Patent Nos. 4,620,215 and 6,472,305 were first cited in the Office Action dated August 9, 2004 in a related co-pending application (Serial No. 10/699,744). A copy of the office action is attached herewith. Please also note that US Patent No. 6,448,645 was also cited in the Office Action (copy enclosed), but was already disclosed in the Information Disclosure Statement filed on November 4, 2003.

Although no fees are believed to be due at this time, it is respectfully requested that any such fees be charged to Deposit Account 50-1147. Also, the Examiner is requested to initial the attached PTO Form-1449 and to return a copy of same to the undersigned attorney as proof that the listed references have been considered and made of record.

Respectfully submitted,

David G. Posz Reg. No. 37,701

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#### **U.S. PATENT DOCUMENTS**

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
	4,620,215	Oct., 1986	Lee, James C.K.		
	6,472,305	Oct., 2002	Ozaki et al.		

# FOREIGN PATENT DOCUMENTS

 _ <u></u>						TRAN	ISLATION
DOCUMENT NUMBER	DATE	COUNTRY	NAME	CLASS	SUB CLASS	YES	NO (Abstract)

<sup>\*</sup> Full English text of the JP Document will be available in machine-translated form from JP (Japanese Patent Office) English language web site at http://www1.ipdl.jpo.go.jp/PA1/cgi-bin/PA1INDEX.

# OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

EXAMINER		DATE CONSIDERED

Rev. 10/94 (Form 3.05)

REFERENCE DESIG